



浙江世菱半导体有限公司
ZHEJIANG SHILING SEMICONDUCTOR CO.,LTD.

产品规格书

Specification of products

产品名称：整流管模块

产品型号：MDC200A-Y01

浙江世菱半导体有限公司
ZHEJIANG SHILING SEMICONDUCTOR CO., LTD.

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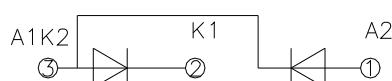
[Http://www.smrshiling.com](http://www.smrshiling.com)

拟制	审核	核准
林益龙	曹剑龙	宗瑞

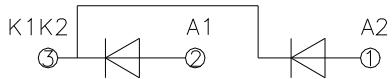
SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T_j (°C)	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Single side cooled, $T_C=100^\circ\text{C}$	150			200	A
$I_{F(RMS)}$	RMS forward current	Single side cooled, $T_C=100^\circ\text{C}$	150			314	A
V_{RRM}	Repetitive peak reverse voltage	V_{RRM} tp=10ms $V_{RsM}= V_{DRM} \& V_{RRM}+200\text{V}$	150		1600		V
I_{RRM}	Repetitive peak current	at V_{RRM}	150			12	mA
I_{FSM}	Surge forward current	10ms half sine wave	150			7.5	KA
I^2t	I^2T for fusing coordination	$V_R=0.6V_{RRM}$				281	$\text{A}^2\text{s} \times 10^3$
V_{FO}	Threshold voltage		150			0.75	V
r_F	Forward slop resistance					0.88	$\text{m}\Omega$
V_{FM}	Peak forward voltage	$I_{FM}=600\text{A}$	25			1.40	V
$R_{th(j-c)}$	Thermal resistance Junction to heatsink	At 180° sine Single side cooled				0.210	$^\circ\text{C}/\text{W}$
V_{iso}	Isolation voltage	50Hz, RM. S, t=1min, I_{iso} : 1mA (max)		2500			V
F_m	Terminal connection torque(M6)				5.0		N.m
	Mounting torque(M6)				5.0		N.m
T_{Stg}	Stored temperature			-40		125	$^\circ\text{C}$
W_t	Weight				380		g
Outline							

OUTLINE DRAWING & CIRCUIT DIAGRAM

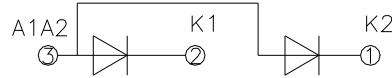
MDC



MDK



MDA



Rating and Characteristic

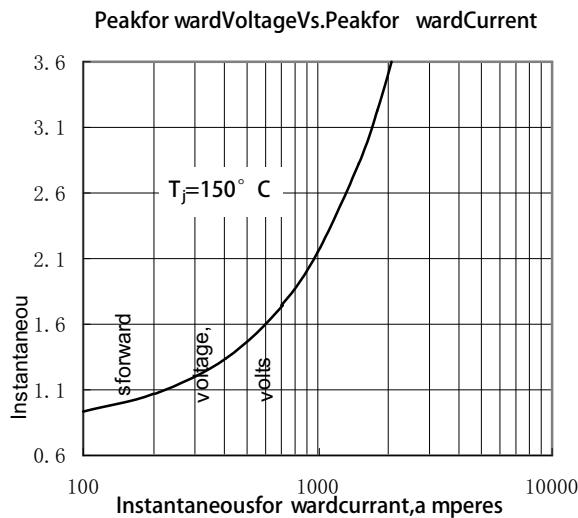


Fig.1

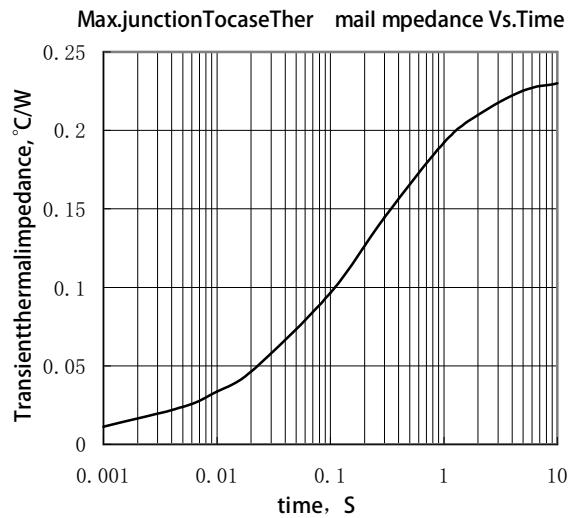


Fig.2

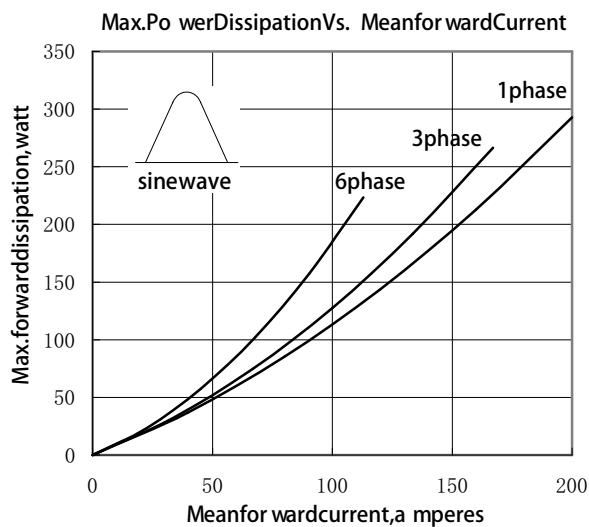


Fig.3

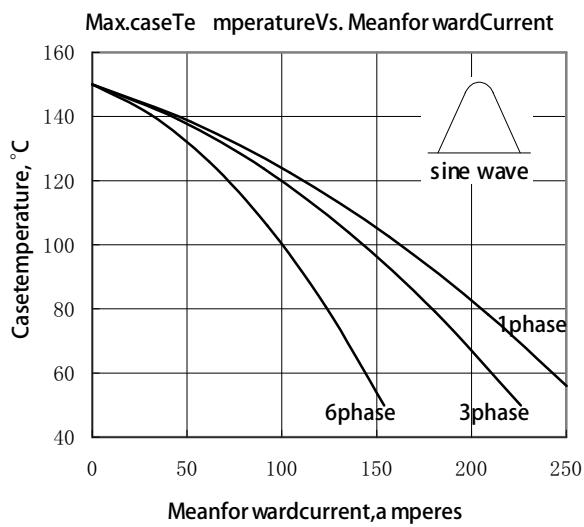


Fig.4

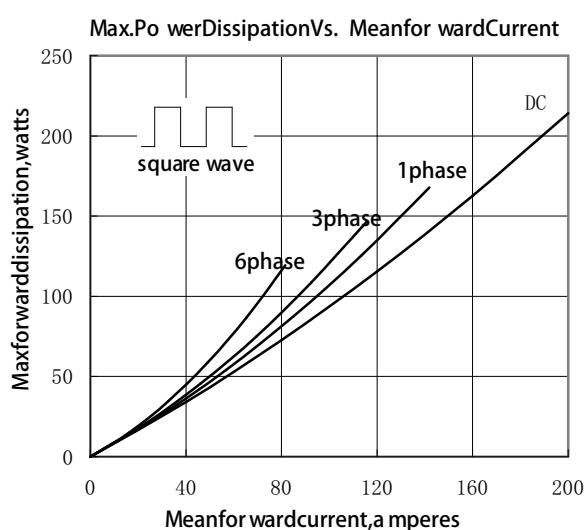


Fig.5

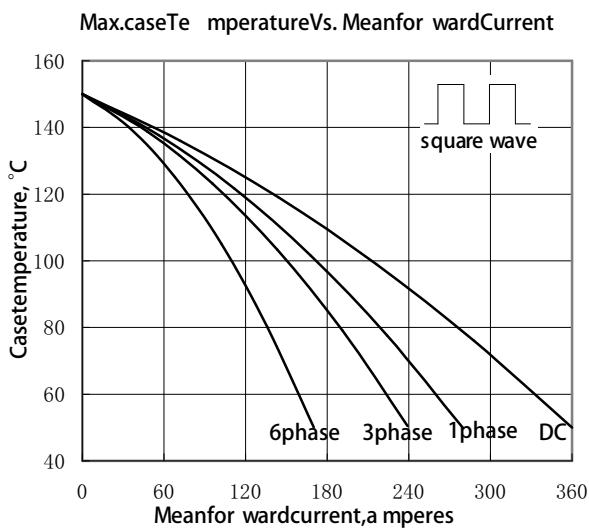


Fig.6

Outside Dimension

